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AMENDMENTS TO THE SPECIFICATION

0037 Shown in Fig. 3 is a schematic cross-sectional diagram of a microelectronic fabrication mask otherwise equivalent to the microelectronic fabrication mask whose schematic cross-sectional diagram is illustrated in Fig. 2, but wherein, in a first instance, the electron beam exposed blanket resist layer 14' has been developed to form a series of patterned resist layers 14a, 14b and ~~14b~~ 14c.

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